



**Product data sheet** 

### 1. General description

Ultrafast power diode in a 2-lead TO220F plastic package.

### 2. Features and benefits

- Fast switching
- Soft recovery characteristic
- Isolated package
- Low forward voltage drop
- High thermal cycling performance

### **3. Applications**

- Output rectifiers in high frequency switched-mode power supplies
- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)

### 4. Quick reference data

Symbol	Parameter	Conditions	Values			Unit	
Absolute	maximum rating						
$V_{\text{RRM}}$	repetitive peak reverse voltage			5	00		V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; square-wave pulse; $T_{h} \leq$ 90 °C	9			А	
I <sub>FSM</sub> non-repetitive peak		$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		100			А
	forward current	$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	110			А	
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 8 A; T <sub>j</sub> = 150 °C		-	0.9	1.03	V
		I <sub>F</sub> = 8 A		-	1.05	1.25	V
		I <sub>F</sub> = 20 A		-	1.2	1.4	V
Dynamic	characteristics						
t <sub>rr</sub>	reverse recovery time	I <sub>F</sub> = 1 A; V <sub>R</sub> = 30 V; dI <sub>F</sub> /dt = 100 A/µs; T <sub>i</sub> = 25 °C		-	50	60	ns

# 5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode	mb	
2	А	anode		К-Ң-А
mb	n.c.	mounting base; isolated	1 2 SOD113 (2-lead TO-220F)	00 <sup>1</sup> aaa020

# 6. Ordering information

Table 3. Ordering information								
Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
	Name		method	quantity	version	issue date		
BYV29X-500	TO220F	BYV29X-500,127	Tube	50	SOD113	28-Aug-2015		

## 7. Marking

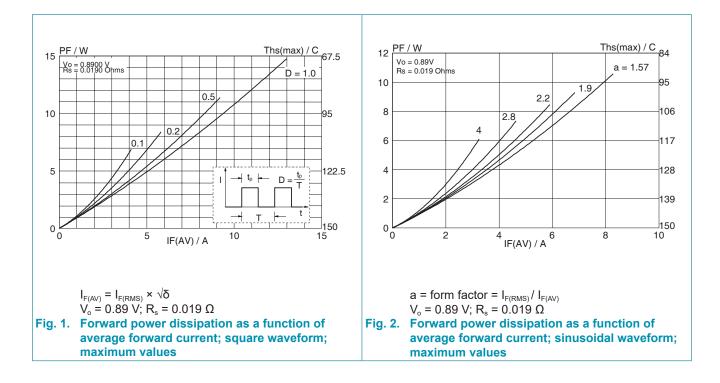
Table 4. Marking codes		
Type number	Marking codes	
	Assembly factory: d	Assembly factory: A
BYV29X-500	BYV29X 500 PJdxxxx xx	BYV29X 500 PJAxxxx xx

### 8. Limiting values

#### Table 5. Limiting values

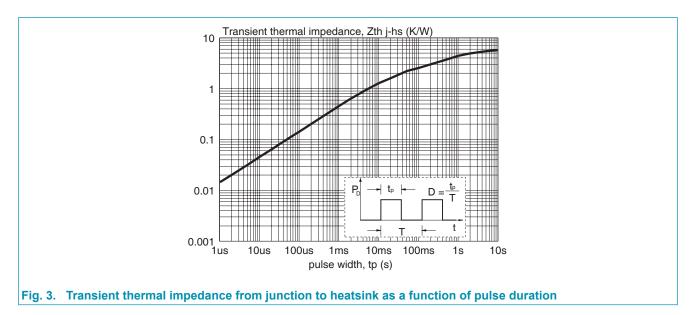
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage		500	V
V <sub>RWM</sub>	crest working reverse voltage		500	V
V <sub>R</sub>	reverse voltage	DC	500	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5 ; square-wave pulse; T <sub>h</sub> ≤ 90 °C	9	А
I <sub>FSM</sub>	non-repetitive peak	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	100	А
	forward current	$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	110	А
T <sub>stg</sub>	storage temperature		-40 to 150	°C
T <sub>j</sub>	junction temperature		150	°C



## 9. Thermal characteristics

Table 6. Th	ermal characteristics		 			
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	thermal resistance	with heatsink compound	-	-	5.5	K/W
	from junction to heatsink	without heatsink compound	-	-	7.2	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient free air	in free air	-	55	-	K/W



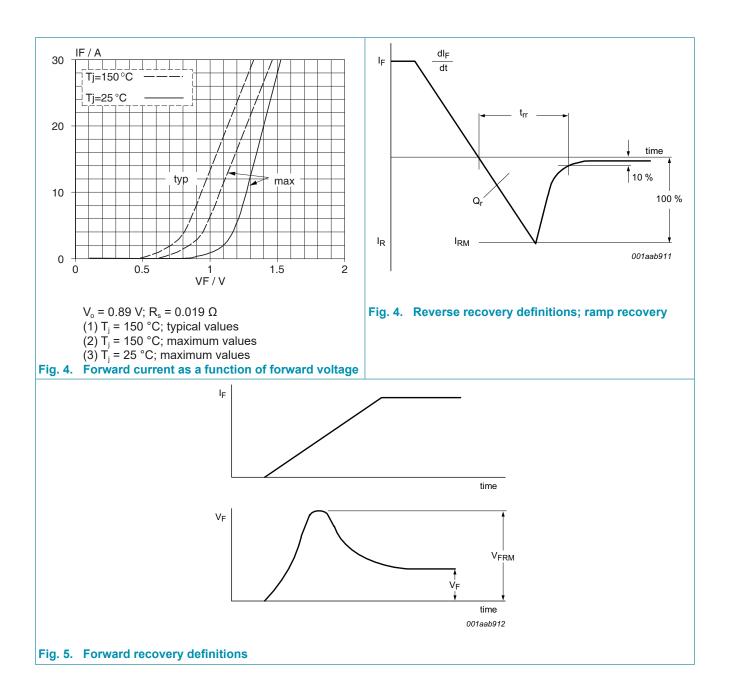
# **10. Isolation characteristics**

Table 7. Iso	olation characteristics					
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
$V_{\text{isol}(\text{RMS})}$	RMS isolation voltage	50 Hz $\leq$ f $\leq$ 60 Hz; RH $\leq$ 65 %; from all pins to external heatsink; sinusoidal waveform; clean and dust free	-	-	2500	V
$C_{isol}$	isolation capacitance	from cathode to external heatsink	-	10	-	pF

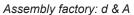
## **11. Characteristics**

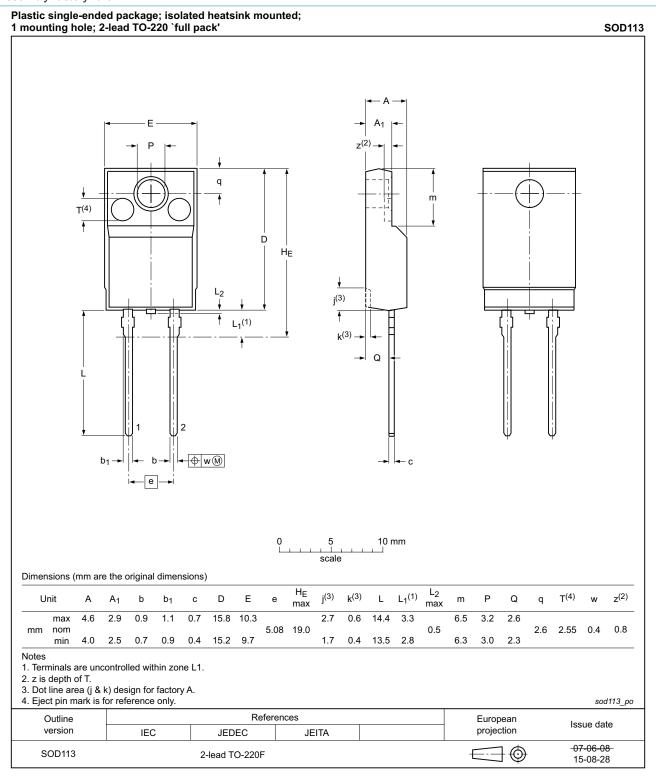
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics	· · · ·				
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 8 A; T <sub>j</sub> = 150 °C	-	0.9	1.03	V
		I <sub>F</sub> = 8 A	-	1.05	1.25	V V µA mA
		I <sub>F</sub> = 20 A	-	1.2	1.4	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C	-	2	50	μA
		V <sub>R</sub> = 600 V; T <sub>j</sub> = 100 °C	-	0.1	0.35	mA
Dynamic	characteristics	· · · · · · · · · · · · · · · · · · ·	I			
Q <sub>r</sub>	recovered charge	$I_F = 2 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 20 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}$	-	40	60	nC
t <sub>rr</sub>	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}$	-	50	60	ns
I <sub>RM</sub>	peak reverse recovery current	$I_F = 10 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A}/\mu\text{s};$ $T_j = 100 \text{ °C}$	-	4	5.5	A
V <sub>fr</sub>	Forward recovery voltage	I <sub>F</sub> = 10 A; dI <sub>F</sub> /dt = 10 A/μs	-	2.5	-	V

BYV29X-500 Ultrafast power diode



## 12. Package outline





## 13. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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